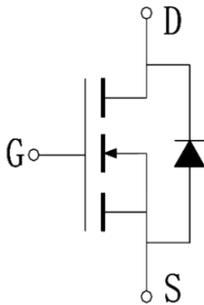




# JX3090K

## N-Channel Enhancement Mode MOSFET

$V_{DS}$	$R_{DS(on)}$ Typ.	$I_D$ Max.
30V	3.1m $\Omega$ @ 10V	90A
	4.7m $\Omega$ @ 4.5V	



Schematic Diagram

### 1.Features

- ◆ 30V MOSFET technology
- ◆ Low on-state resistance
- ◆ Fast switching
- ◆  $V_{GS} \pm 20V$

### 2.Applications

- ◆ Power Switching Application
- ◆ Load Switching



TO-252  
Pin Description

### 3.Package Marking and Ordering Information

Part no.	Marking	Package	PCS/Reel	PCS/CTN.
JX3090K	JX3090K	TO-252	2,500	25,000

### 4.Absolute Max Ratings at $T_a=25^\circ C$ (Note1)

Parameter	Symbol	Maximum	Units
Drain to Source Voltage	$V_{DSS}$	30	V
Gate to Source Voltage	$V_{GSS}$	$\pm 20$	V
Drain Current (DC)	$I_D$	90	A
Drain Current (Pulse), $PW \leq 300\mu s$	$I_{DP}$	360	A
Total Dissipation	$P_D$	65	W
Avalanche Energy, Single Pulsed	$E_{AS}$	240	mJ
Junction Temperature	$T_j$	175	$^\circ C$
Storage Temperature	$T_{stg}$	-55 to +175	$^\circ C$

Note 1: Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**5. Thermal Resistance Ratings**

Parameter	Symbol	Value	Unit
Junction to case	$R_{\theta JC}$	2.3	$^{\circ}C/W$

Note 2 : When mounted on 1 inch square copper board  $t \leq 10$ sec The value in any given application depends on the user's specific board design.

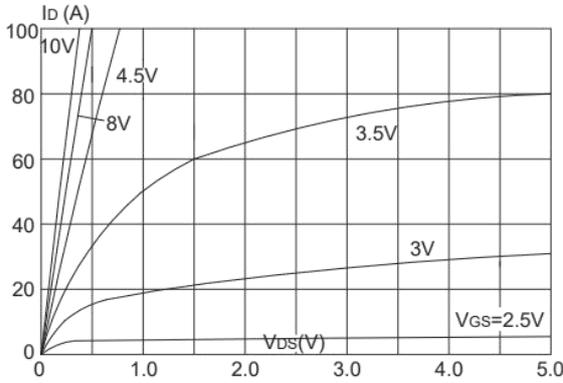
**6. Electrical Characteristics at  $T_a=25^{\circ}C$  (Note 3)**

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 250\mu A, V_{GS} = 0V$	30			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 30V, V_{GS} = 0V$			1	$\mu A$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{SS} = 0V$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_{DS}=250\mu A$	1.0	1.6	2.5	V
Static Drain to Source On-State Resistance	$R_{DS(on)}$	$I_D = 30A, V_{GS} = 10V$	-	3.1	3.6	m $\Omega$
		$I_D = 20A, V_{GS} = 4.5V$	-	4.7	7.5	m $\Omega$
Input Capacitance	$C_{iss}$	$V_{GS}=0V,$ $V_{DS}=15V,$ Frequency=1.0MHz		1700		pF
Output Capacitance	$C_{oss}$				320	pF
Reverse Transfer Capacitance	$C_{rss}$				300	pF
Turn-ON Delay Time	$t_{d(on)}$	$V_{DS} = 15V, I_D = 30A,$ $V_{GS} = 10V, R_G = 3\Omega$		21		ns
Rise Time	$t_r$				32	ns
Turn-OFF Delay Time	$t_{d(off)}$				60	ns
Fall Time	$t_f$				34	ns
Total Gate Charge	$Q_g$	$V_{DS} = 15V,$		45		nC
	$Q_{gs}$	$V_{GS} = 10V,$		3		nC
	$Q_{gd}$	$I_D = 30A$		15		nC
Diode Forward Voltage	$V_{FSD}$	$I_S = 30A, V_{GS} = 0$	0.4	0.85	1.2	V

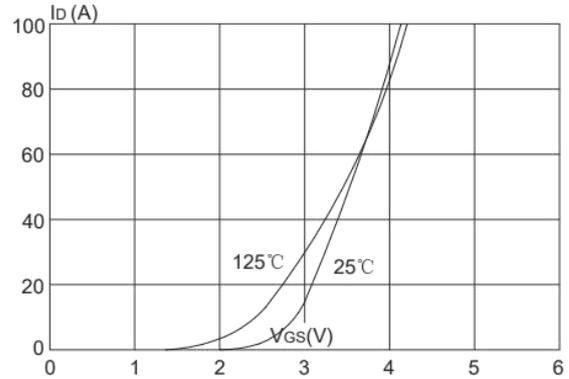
Note 3 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



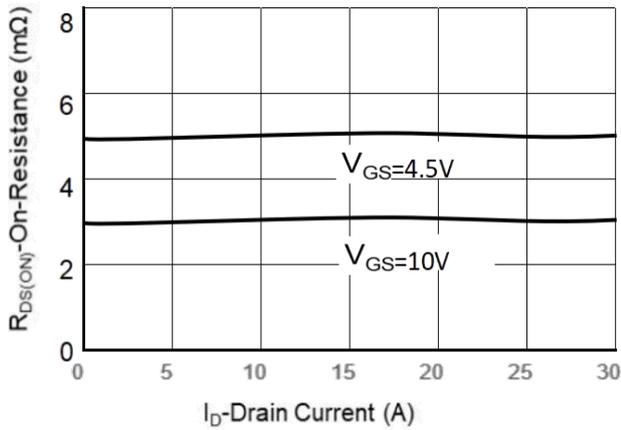
### 7. Typical electrical and thermal characteristics



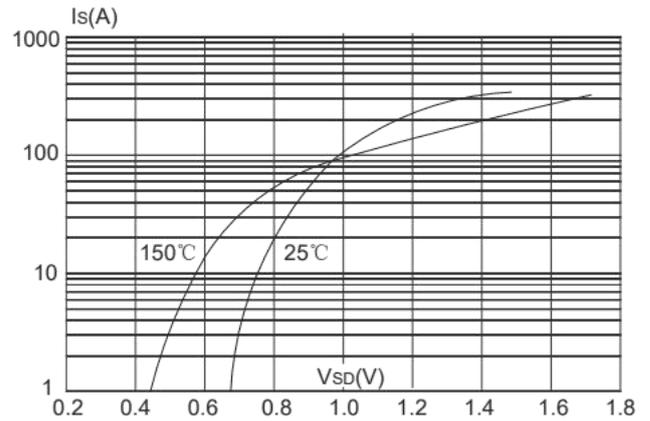
Output Characteristics



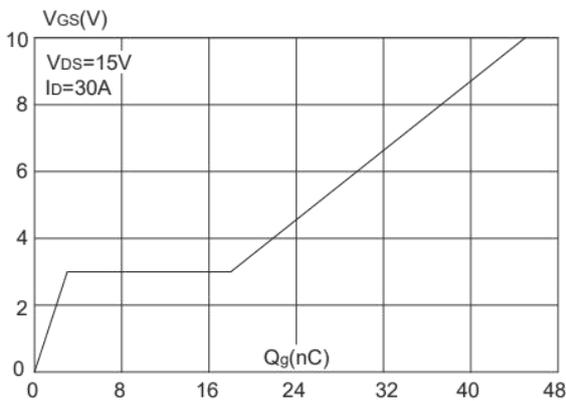
Transfer Characteristics



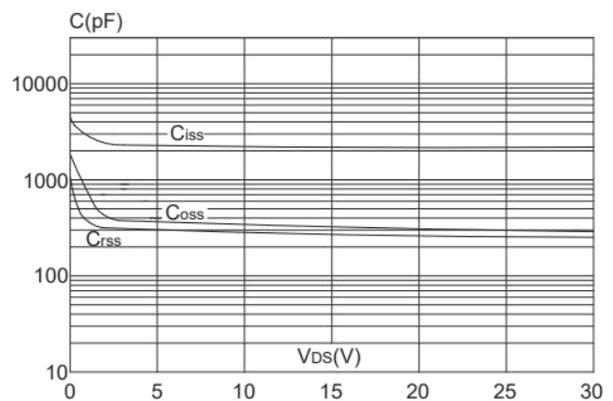
Rdson-Drain Current



Body Diode Characteristic



Gate Charge

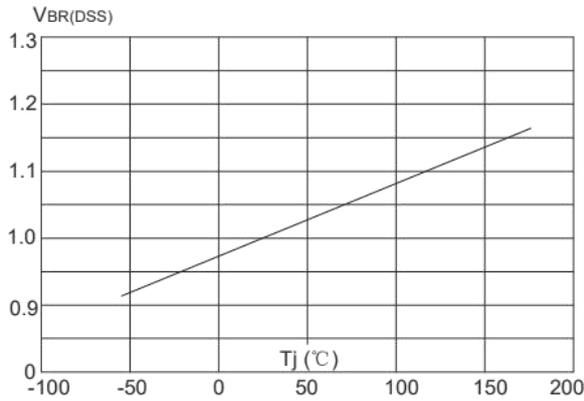


Capacitance Characteristics

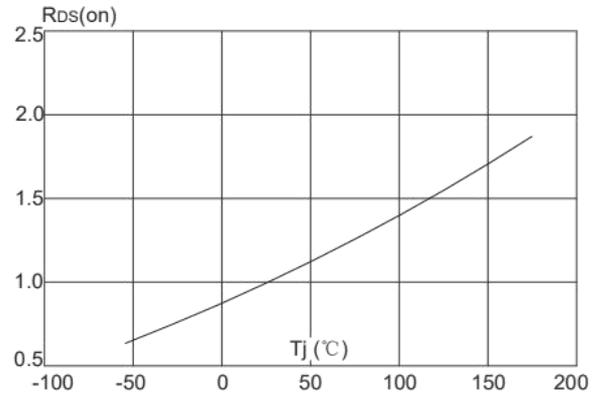


**JX3090K**

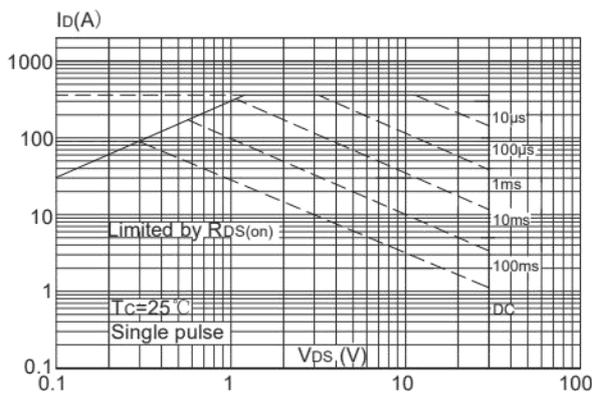
**N-Channel Enhancement Mode MOSFET**



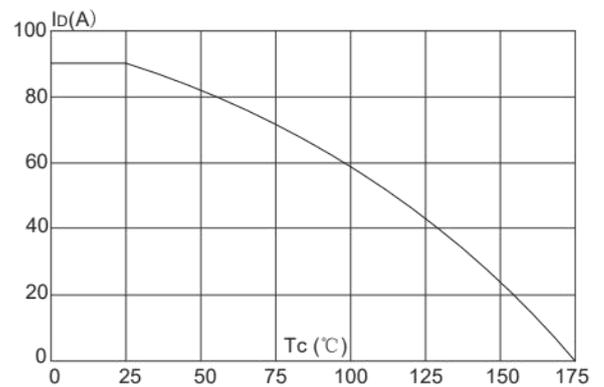
**Normalized Breakdown Voltage vs. Junction Temperature**



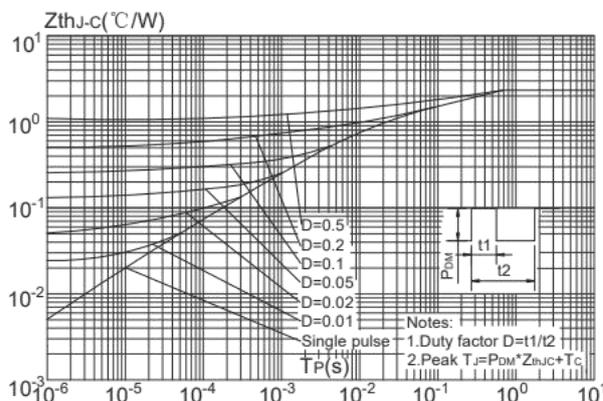
**Normalized on Resistance vs. Junction Temperature**



**Maximum Safe Operating Area**



**Maximum Continuous Drain Current vs. Case Temperature**



**Maximum Effective Transient Thermal Impedance, Junction-to-Case**



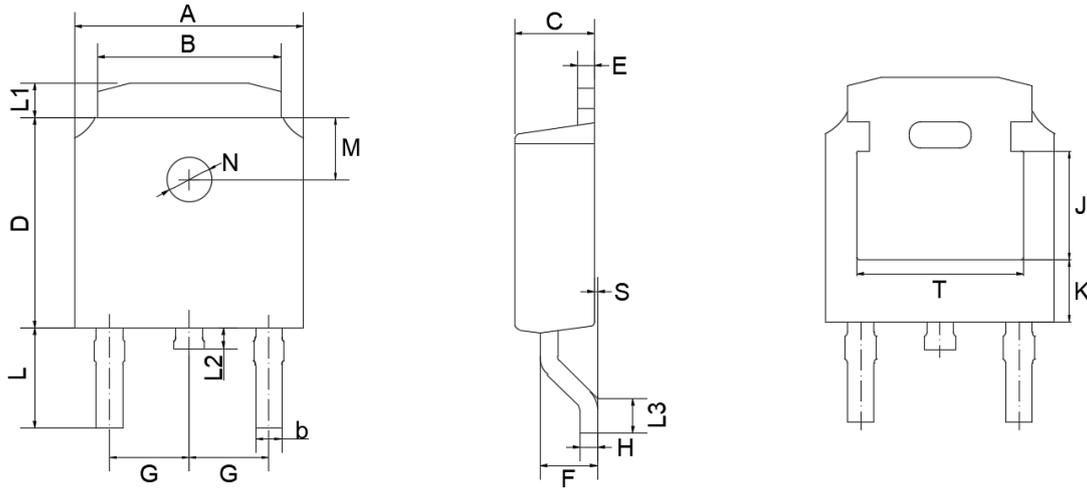


**JX3090K**

**N-Channel Enhancement Mode MOSFET**

**8.Package Dimensions**

TO-252(D-PAK) Package Outline Dimensions



TO-252(D-PAK) mechanical data

UNIT		A	B	b	C	D	E	F	G	H	L	L1	L2	L3	S	M	N	J	K	T
mm	max	6.7	5.5	0.86	2.5	6.3	0.6	1.8	2.29 TYPICAL	0.55	3.1	1.4	1.0	1.75	0.1	1.8 TYPICAL	1.3 TYPICAL	3.16	1.80	4.83
	min	6.3	5.1	0.66	2.1	5.9	0.4	1.3		0.45	2.7	0.8	0.6	1.40	0.0			ref.	ref.	ref.
mil	max	264	217	33	98	248	24	71	90 TYPICAL	22	122	55	39	69	4	71 TYPICAL	51 TYPICAL	124	71	190
	min	248	201	26	83	232	16	51		18	106	31	24	55	0			ref.	ref.	ref.

